NSN 5961-01-153-9422

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-153-9422 **Inclosure Material:** Glass **Overall Length:** Between 0.360 inches and 0.375 inches **Terminal Length:** 1.100 inches **Overall Diameter:** 0.200 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 365.0 breakdown voltage, dc and 300.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 6.00 amperes source cutoff current universal **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 97942-584r090 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: